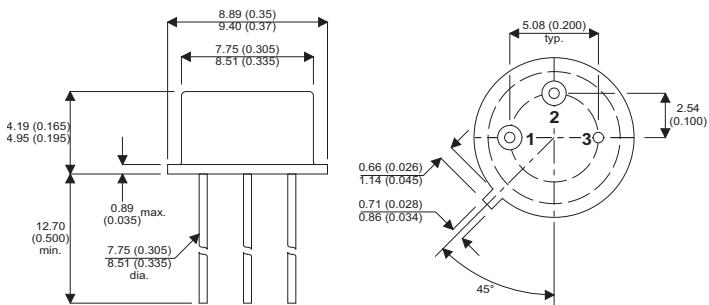


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IP79M05AJX**

MECHANICAL DATA

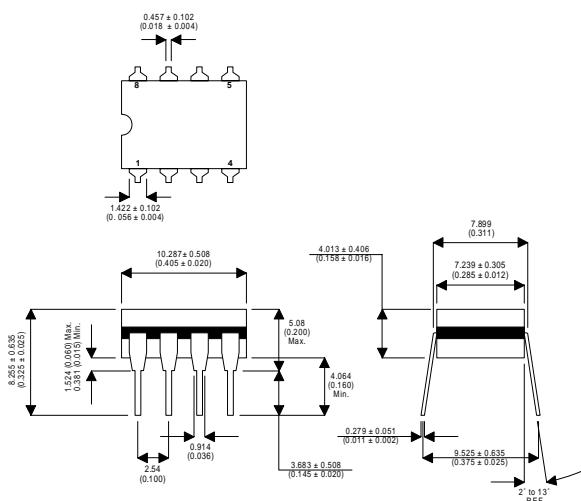


H Package - TO-39 Metal

Pin 1 = Ground

Pin 2 = Vout

Pin 3 = Vin



J Package = 8 Pin Ceramic DIP

Pin 1 = Ground

Pin 5 = N/C

Pin 2 = N/C

Pin 6 = Vin

Pin 3 = N/C

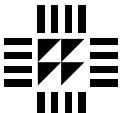
Pin 7 = N/C

Pin 4 = Vout

Pin 8 = N/C

ABSOLUTE MAXIMUM RATINGS ($T_{case} = 25^\circ\text{C}$ unless otherwise stated)

V_I	DC Input Voltage	$V_O = -5\text{V}$	35V
P_D	Power Dissipation		Internally limited
T_j	Operating Junction Temperature Range		-55°C to +150°C
	Maximum Junction Temperature		150°C
T_{stg}	Storage Temperature Range		-65°C to +150°C
T_L	Lead Temperature (Soldering, 10 sec)		300°C



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ELECTRICAL CHARACTERISTICS ($T_j = 25^\circ\text{C}$ unless stated)

Parameter	Test Conditions	Min.	Typ.	Max.	Unit
V_O Output Voltage*	$I_O = 100\text{mA}$ $V_{IN} = 10\text{V}$	- 4.95	- 5	- 5.05	V
	$I_O = 5\text{mA}$ to 350mA $P_D \leq P_{MAX}$ $T_j = -55$ to $+150^\circ\text{C}$	- 4.85		- 5.15	
ΔV_O Line Regulation*	$I_O = 200\text{mA}$ $(V_{IN} = -7$ to $-25\text{V})$	3	10		mV
	$I_O = 200\text{mA}$ $T_j = -55$ to $+150^\circ\text{C}$ $(V_{IN} = -8$ to $-25\text{V})$	3	10		
	$I_O = 500\text{mA}$ $(V_{IN} = 8$ to $12\text{V})$	3	10		
ΔV_O Load Regulation*	$I_O = 5\text{mA}$ to 500mA $V_{IN} = 10\text{V}$ $T_j = -55$ to $+150^\circ\text{C}$		5	50	mV
I_d Quiescent Current*	$I_O = 350\text{mA}$ $V_{IN} = 10\text{V}$ $T_j = -55$ to $+150^\circ\text{C}$		4	6	mA
ΔI_Q Quiescent Current Change*	$I_O = 5$ to 500mA $V_{IN} = 10\text{V}$ $T_j = -55$ to $+150^\circ\text{C}$		0.1	0.5	mA
	$I_O = 200\text{mA}$ $T_j = -55$ to $+150^\circ\text{C}$ $(V_{IN} = -8$ to $-25\text{V})$		0.2	0.8	mA
V_N Output Noise Voltage	$f = 10\text{Hz}$ to 100kHz		40	200	μV
$\frac{\Delta V_{IN}}{\Delta V_O}$ Ripple Rejection	$f = 120\text{Hz}$ $I_O = 300\text{mA}$ $(V_{IN} = -8$ to $-18\text{V})$	65	80		dB
	$f = 120\text{Hz}$ $I_O = 100\text{mA}$ $T_j = -55$ to $+150^\circ\text{C}$ $(V_{IN} = -8$ to $-8\text{V})$	65	80		
Dropout Voltage*	$I_O = 350\text{mA}$		2	2.5	V
I_{SC} Short Circuit Current*	$V_{IN} = 35\text{V}$		600	1200	mA
I_{PK} Peak Output Current*	$V_{IN} = 10\text{V}$		0.7	2.4	A
Average Temperature Coefficient of Output Voltage*	$I_O = 5\text{mA}$		0.5	2.0	$\text{mV}/^\circ\text{C}$

* Pulse Test: $t_p \leq 10\text{ms}$, $\delta \leq 5\%$.

All characteristics are measured with a capacitor across the input of $0.22\mu\text{F}$ and a capacitor across the output of $0.1\mu\text{F}$. Output Voltage changes due to changes in internal temperature must be taken into account separately.

Although power dissipation is internally limited, these specifications apply for up to 2W for the TO-39 package, and 1.05W for the CERDIP (J package).

THERMAL DATA

$R_{THj-case}$	Thermal Resistance Junction – Case	TO-39 (H Package)	$20^\circ\text{C} / \text{W}$ Typ.
$R_{THj-amb}$	Thermal Resistance Junction – Ambient	CERDIP (J Package)	$120^\circ\text{C} / \text{W}$ Typ.
	Derate above 25°C	CERDIP (J Package)	$8.4 \text{ mW} / ^\circ\text{C}$